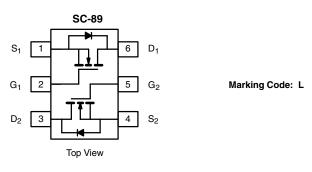


**Vishay Siliconix** 

## N-Channel 20 V (D-S) MOSFET

PRODUCT SI	JMMARY	
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω)	I <sub>D</sub> (mA)
20	5 at V <sub>GS</sub> = 4.5 V	200
	7 at V <sub>GS</sub> = 2.5 V	175
	9 at V <sub>GS</sub> = 1.8 V	150
	10 at V <sub>GS</sub> = 1.5 V	50



Ordering Information: Si1034X-T1-GE3 (Lead (Pb)-free and Halogen-free)

#### FEATURES

- Halogen-free According to IEC 61249-2-21
  Definition
- TrenchFET<sup>®</sup> Power MOSFET: 1.5 V Rated
- Low-Side Switching
- Low On-Resistance: 5  $\Omega$
- Low Threshold: 0.9 V (typ.)
- Fast Switching Speed: 35 ns (typ.)
- 1.5 V Operation
- Gate-Source ESD Protected: 2000 V
- Compliant to RoHS Directive 2002/95/EC

#### BENEFITS

- Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Battery Voltage Operation

#### **APPLICATIONS**

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- Battery Operated Systems
- Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

<b>ABSOLUTE MAXIMUM RATINGS</b>	$(T_A = 25 \ ^{\circ}C, unle$	ss otherwise r	noted)			
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	20		V	
Gate-Source Voltage		V <sub>GS</sub>	± 5			
	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	190	180		
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 85 °C		140	130		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	650		mA	
Continuous Source Current (Diode Conduction)		۱ <sub>S</sub>	450	380		
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	P <sub>D</sub>	280	250	mW	
	T <sub>A</sub> = 85 °C		145	130		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000		V	

Notes:

a. Surface mounted on FR4 board.

b. Pulse width limited by maximum junction temperature.



FREE

### Vishay Siliconix



SPECIFICATIONS (T <sub>A</sub> =	25 °C, unl	ess otherwise noted)				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	0.40		1.2	V
Gate-Body Leakage	lasa	$V_{DS} = 0 V, V_{GS} = \pm 2.8 V$		± 0.5	± 1.0	
Gale-Douy Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 4.5 V$		± 1.0	± 3.0	μA
Zero Gate Voltage Drain Current	Inco	$V_{DS} = 16 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		1	500	nA
Zero Gale Voltage Drain Current	IDSS	$V_{DS}$ = 16 V, $V_{GS}$ = 0 V, $T_{J}$ = 85 °C			10	μA
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 4.5 V$	250			mA
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$			5	
Drain-Source On-State	Р	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 175 mA			7	0
Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 1.8 V, I <sub>D</sub> = 150 mA			9	Ω S V
		V <sub>DS</sub> = 1.5 V, I <sub>D</sub> = 40 mA			10	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 200 mA		0.5		
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = 150 mA, V <sub>GS</sub> = 0 V			1.2	
Dynamic <sup>b</sup>						
Total Gate Charge	Qg			750		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = 10 V, $V_{GS}$ = 4.5 V, $I_D$ = 150 mA		75		pC
Gate-Drain Charge	Q <sub>gd</sub>			225		
Turn-On Delay Time	t <sub>d(on)</sub>				50	ns
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 47 $\Omega$			25	
Turn-Off Delay Time	t <sub>d(off)</sub>	$\rm I_D \cong 200~mA,~V_{GEN}$ = 4.5 V, $\rm R_g$ = 10 $\Omega$			50	
Fall Time	t <sub>f</sub>				25	

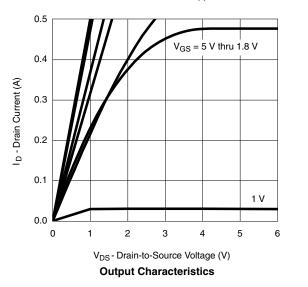
Notes:

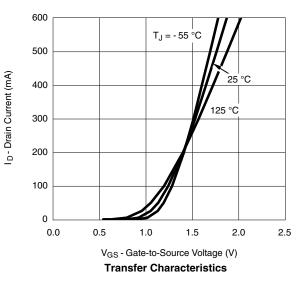
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

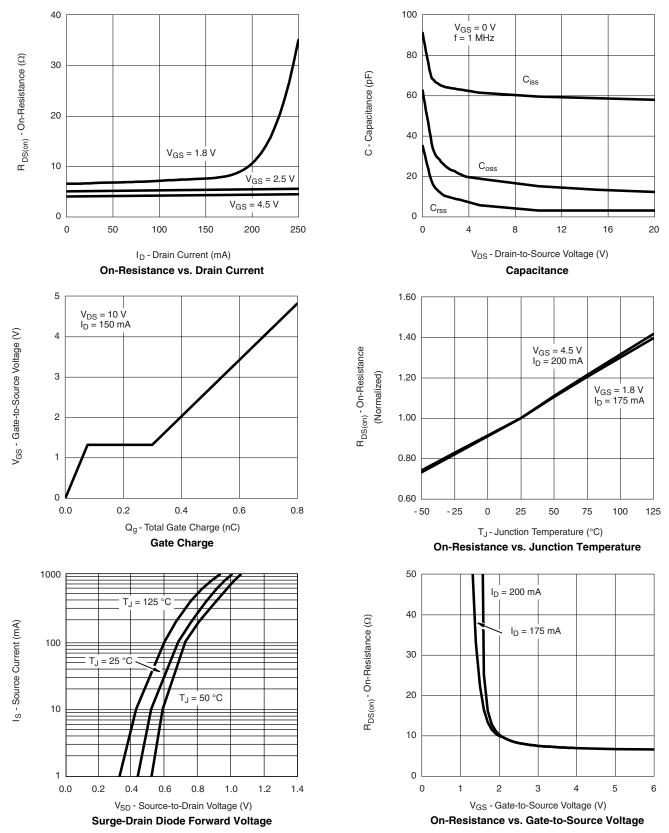
#### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)





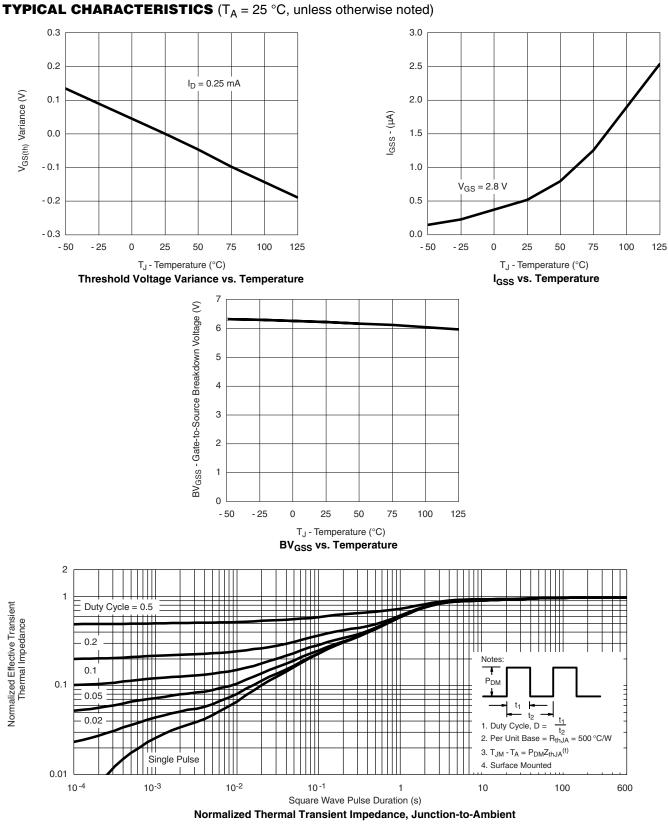


#### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



### Si1034X

### Vishay Siliconix



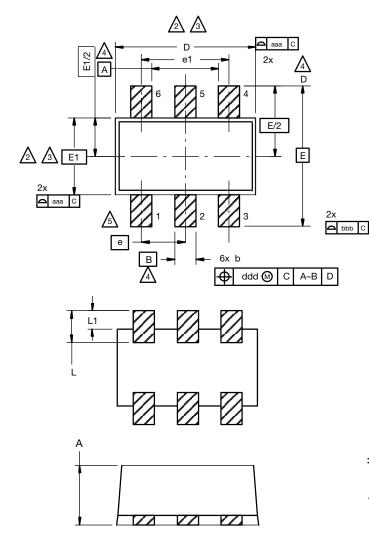
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?71427">www.vishay.com/ppg?71427</a>.





Vishay Siliconix

#### SC-89 6-Leads (SOT-563F)



Notes

- 1. Dimensions in millimeters.
- Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

A Datums A, B and D to be determined 0.10 mm from the lead tip.

 $\triangle$  Terminal numbers are shown for reference only.

These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.









DIM.	MILLIMETERS			
	MIN.	NOM.	MAX.	
А	0.56	0.58	0.60	
A1	0	0.02	0.10	
b	0.15	0.22	0.30	
С	0.10	0.14	0.18	
D	1.50	1.60	1.70	
E	1.50	1.60	1.70	
E1	1.15	1.20	1.25	
е	0.45	0.50	0.55	
e1	0.95	1.00	1.05	
L	0.25	0.35	0.50	
L1	0.10	0.20	0.30	
C14-0439-Rev DWG: 5880	v. C, 11-Aug-14			

Revision: 11-Aug-14

1 For technical questions, contact: <u>analogswitchtechsupport@vishay.com</u> Document Number: 71612

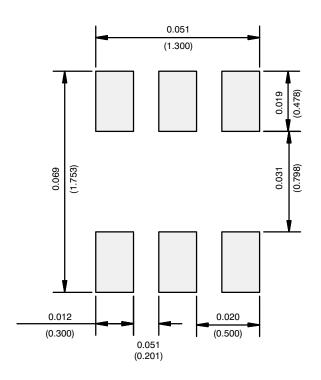
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



# Application Note 826

Vishay Siliconix

#### **RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead**



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



Vishay

### Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay: SI1034X-T1 SI1034X-T1-E3 SI1034X-T1-GE3